Form PTO 1449 (Modified)	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY DOCKET NO.	SERIAL NO.
		249420US2	10/784,932
LIST OF REFERENCES CITED BY APPLICANT		APPLICANT: Kazuo NAKAJIMA, et al.	
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■ Additional References sheet(s) attached

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U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
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FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES	TRANSLATION NO
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	AP					
	AQ					
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	AV					

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	AZ	☐ Additional References sheet(s) attached

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